

600V, 7A, Trench FS II Fast IGBT

General Description

Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 600V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

Features

- Trench FSII Technology Offering
- Very low V_{CE(sat)}
- High speed switching
- Positive temperature coefficient in V_{CE(sat)}
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

- Air Condition
- Inverters
- Motor drives

Package Marking and Ordering Information

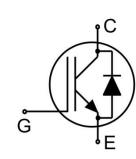
Device	Device Package	Device Marking		
NCE07TD60B	TO-220	NCE07TD60B		



TO-220

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Value	Units	
VCES	Collector-Emitter Voltage	600	V	
V _{GES}	Gate- Emitter Voltage	±30	V	
I	Collector Current	14	A	
lc	Collector Current @T _c = 100 °C	7	A	
I _{Cpuls}	Pulsed Collector Current, t _p limited by T _{jmax}	21	A	
-	turn off safe operating area, V_{CE} =600V, T _J =175°C	21	A	
I _F	Diode Continuous Forward Current @T _c = 100 °C	7	A	
I _{FM}	Diode Maximum Forward Current	21	A	
Power Dissipation @ T _c = 25°C		87	W	
PD	Power Dissipation @T _c = 100 °C	43.5	W	
T _J ,T _{stg}	Operating Junction and Storage Temperature Range	-55 to +175	°C	
T_L	Maximum Temperature for Soldering	260	°C	
t _{sc}	Short circuit withstand time V_{GE} =15V, $V_{CC} \le 400V$, Allowed number of short circuits<1000Time between short circuits: $\ge 1.0s$, $T_j \le 150^{\circ}C$	5	us	



Schematic diagram



Thermal Characteristic

Symbol	Parameter	Value	Units
R _{0JC}	Thermal Resistance, Junction to case for IGBT	1.71	°C/W
R _{0JC}	Thermal Resistance, Junction to case for Diode	2.50	°C/W
R _{0JA}	Thermal Resistance, Junction to Ambient	62	°C/W

Electrical Characteristics (Tc=25°C unless otherwise noted)

Oursela e l	Devenueter	Conditions		Value			
Symbol	Parameter			Min.	Тур.	Max.	Units
Static Chara	cteristics					· · ·	
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	V _{GE} =0V	,I _{CE} =1mA	600			V
I _{CES}	Collector-Emitter Leakage Current	V _{GE} =0V,	V _{CE} =600V			4	uA
I _{GES(F)}	Gate to Emitter Forward Leakage	V _{GE} =+30	V,V _{CE} =0V			200	nA
I _{GES(R)}	Gate to Emitter Reverse Leakage	V _{GE} =-30	V,V _{CE} =0V			200	nA
V _{CE(sat)}	Collector-Emitter Saturation Voltage	Ic=5A	T _j =25°C		1.7	1.9	V
· OE(out)		V_{GE} =15V	T _j =175°C		1.9		V
$V_{\text{GE(th)}}$	Gate Threshold Voltage	lc=1mA	,V _{CE} =V _{GE}	4.0	5.0	6.0	V
Dynamic Cha	aracteristics						
Cies	Input Capacitance	- V _{CE} =25V, V _{GE} =0V, f=1MHz			675		pF
Coes	Output Capacitance				22		
Cres	Reverse Transfer Capacitance	1-1			13		
Qg	Total Gate Charge	V _{CC} =480V, I _C =7A, V _{GE} =15V			28		nC
Q _{ge}	Gate to Emitter Charge				8		
Q _{gc}	Gate to Collector Charge				13		
I _{C(SC)}	Short circuit collector current Max.1000 short circuits Time between short circuits: \geq 1.0s	V _{GE} =15V,V _{CC} ≪400V, t _{SC} ≪5us,T _j ≪150°C			34		А
Switching C	haracteristics						
t _{d(ON)}	Turn-on Delay Time				20		
tr	Rise Time				15		ns
$t_{d(OFF)}$	Turn-Off Delay Time	Vcc=400V,Ic=7A,			73		115
t _f	Fall Time	V _{GE} =0/15V, R _g =5Ω			18		
Eon	Turn-On Switching Loss	Inductive Load			0.21		
E _{off}	Turn-Off Switching Loss				0.10		mJ
E _{ts}	Total Switching Loss				0.31		

Electrical Characteristics of the Diode (T_c = 25°C unless otherwise specified)

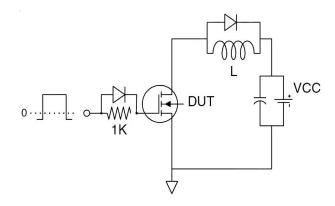
Symbol	Parameter	Conditions	Rating			Unito
		Conditions	Min.	Тур.	Max.	Units
VFM	Diode Forward Voltage	I _F =7A		1.75	2.40	V
Trr	Reverse Recovery Time	I⊧=7A,		230		ns
IRRM	IRRM Diode Peak Reverse Recovery Current			3.5		А
Qrr	Reverse Recovery Charge	di/dt=200A/us		0.44		uC
Pulse width t _t	,≤380µs,δ≤2%					



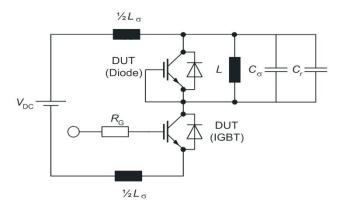


Test Circuit

1) Gate Charge Test Circuit

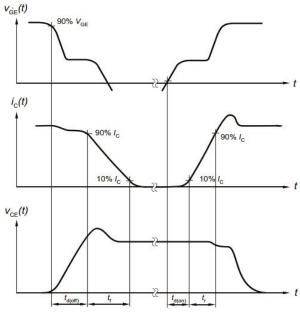


2) Switch Time Test Circuit

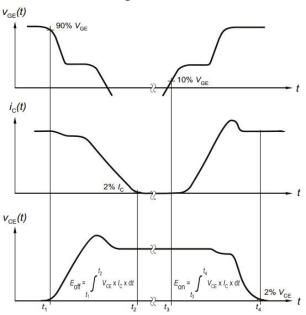


Switching characteristics

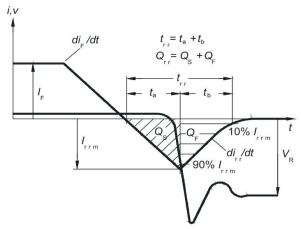
1) Definition of switching times



2) Definition of switching losses



3) Definition of diode switching characteristics





Typical Electrical and Thermal Characteristics

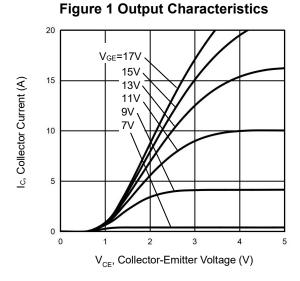
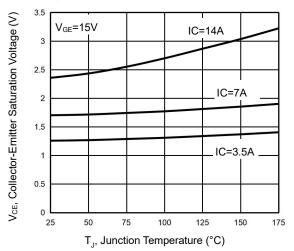
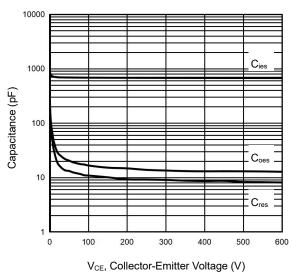


Figure 3 V_{CEsat} vs. Case Temperature







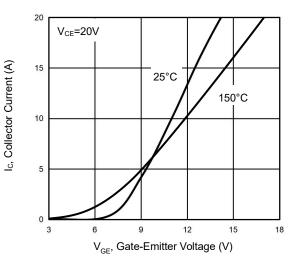
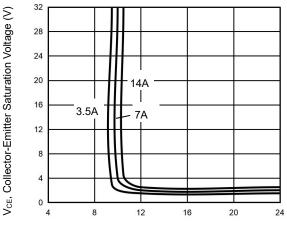


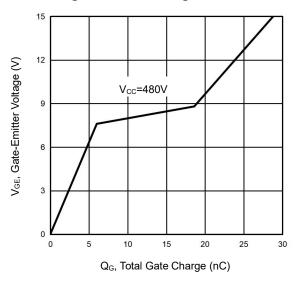
Figure 2 Transfer Characteristics

Figure 4 Saturation Voltage vs. V_{GE}



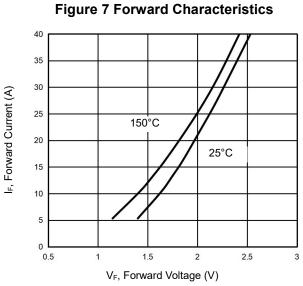
V_{GE}, Gate-Emitter Voltage (V)

Figure 6 Gate charge waveform

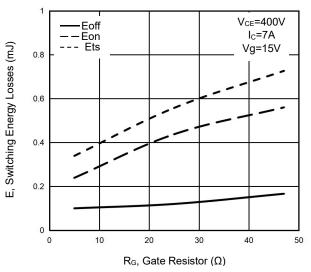




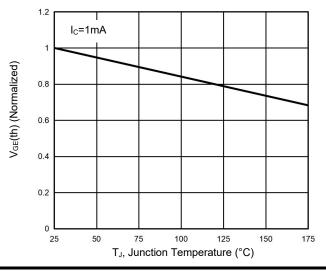
Typical Electrical and Thermal Characteristics











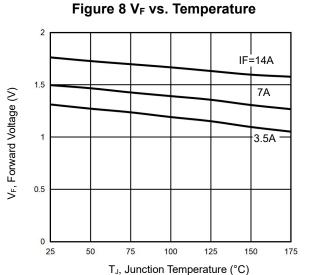


Figure 10 Typical Switching Times as a Function of Junction Temperature

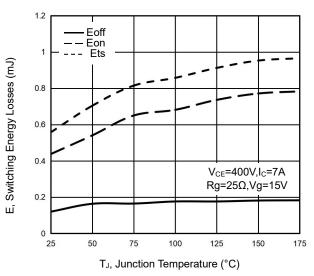
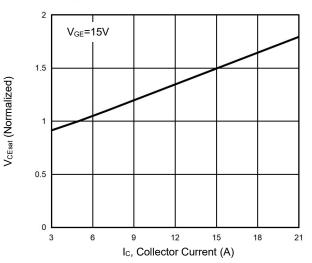


Figure 12 Typical Collector-emitter Saturation Voltage as a function of Collector Current



Wuxi NCE Power Co., Ltd



Typical Electrical and Thermal Characteristics

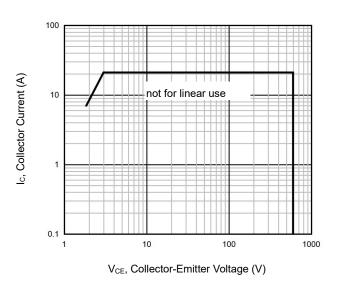
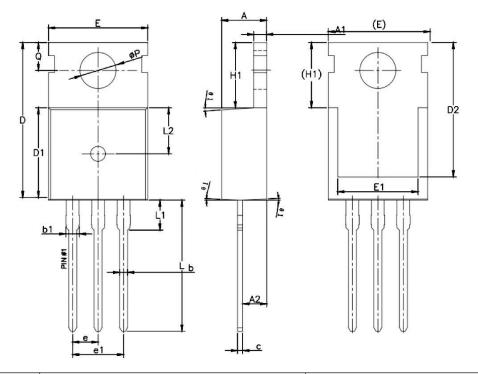


Figure 13 Forward Bias Safe Operating Area



TO-220-P Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
Gymbol	Min.	Max.	Min.	Max.	
Α	4.40	4.60	0.17	0.18	
A1	1.27	1.33	0.05	0.05	
A2	2.30	2.50	0.09	0.10	
b	0.70	0.90	0.03	0.04	
b1		1.40		0.06	
с	0.45	0.60	0.01	0.02	
D	15.30	16.10	0.60	0.63	
D1	9.10	9.30	0.36	0.37	
D2	13.10	13.70	0.52	0.54	
E	9.70	10.20	0.38	0.40	
E1	7.80	8.20	0.31	0.32	
е	2.54	4BSC	0.10BSC		
e1	5.08	5.08BSC 0.20		BSC	
H1	6.30	6.70	0.25	0.26	
L	12.78	13.38	0.50	0.53	
L1		3.50		0.14	
L2	4.60REF		0.18REF		
ΦΡ	3.55	3.65	0.13	0.14	
Q	2.73	2.87	0.10 0.11		
Θ1	1°	5°	0.04	0.20	





Attention:

- Any and all NCE power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE power representative nearest you before using any NCE power products described or contained herein in such applications.
- NCE power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE power products described or contained herein.
- Specifications of any and all NCE power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. NCE power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE power product that you intend to use.
- This catalog provides information as of Sep.2010. Specifications and information herein are subject to change without notice.